Photon Coupled Isolator MOC3020-MOC3023

Ga As Infrared Emitting Diode & Light Activated Triac Driver

The GE Solid State MOC3020-MOC3023 series consists of a gallium arsenide infrared emitting diode coupled with a light activated silicon bilateral switch, which functions like a triac, in a dual-in-line package.

These devices are especially designed for triggering power triacs while maintaining dielectric isolation from the trigger control circuit. They are mounted in dual-in-line packages. These devices are also available in Surface-Mount packaging.

absolute maximum ratings: (25°C)

INFRARED EMITTING DIODE				
Power Dissipation	*100	milliwatts		
Forward Current (Continuous)	50	milliamps		
Forward Current (Peak) (Pulse width 1 µsec, 300 pps)	3	amperes		
Reverse Voltage	3	volts		
*Derate 1.33mW/°C above 25°C ambient.				

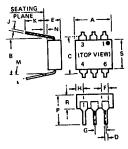
OUTPUT DRIVER						
Off-State Output Terminal Voltage	400	Volts				
On-State RMS Current (Full Cycle Sine Wave, 50 to 60 Hz)	100	milliamps				
Peak Nonrepetitive Surge Current (PW = 10 ms, DC = 10%)	1, 2	amperes				
Total Power Dissipation @ T _A = 25°C	**300	milliwatts				
**Derate 4.0 mW/°C above 25°C ambient.						

TOTAL DEVICE

Storage Temperature -55°C to +150°C Operating Temperature -40°C to +100°C Lead Soldering Time (at 260°C) 10 seconds Isolation Surge Voltage: 7500VAC (Input to Output) (Peak AC Voltage, 60 Hz, 5 second duration)

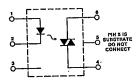
Covered under U.L. component recognition program, reference file E51868





	MILLIMETERS		INCHES		1
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	8,38	8.89	.330	.350	1
A B	7.62	7.62 REF.		REF.	1 1
- c		8 64		.340	2
Ď	.406	.508	016	020	
F		5.08	-	.200	3
D E F	10,1	1.78	.040	.070	
G	2.28	2.80	,090	.110	
H		2.16	-	.085	4
G H J	.203	305	008	.012	
K	2.54		.100	_	1
M		15°	_	15°	
N	.381	<u> </u>	.015		
P		9,53		,375	1
Ř	2.92	3 43	.115	.135	1
Š	6.10	6.86	.240	.270	1

OTES INSTALLED POSITION LEAD CENTERS. OVERALL INSTALLED DIMENSION THESE MEASUREMENTS ARE MADE FROM THE SEATING



MOC3020-MOC3023

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individual electrical characteristics (25°C)

EMITTER	SYMBOL	TYP.	MAX.	UNITS
Forward Voltage (I _F = 10 mA)	V _F	1.2	1.5	volts
Reverse Current (V _R = 3V)	\mathbf{I}_{R}	-	100	microamps
Capacitance (V = O, f = 1 MHz)	C,	50		picofarads

DETECTOR See Note 1		SYMBOL	TYP.	MAX.	UNITS
Peak Off-State Current	V _{DRM} 400 V	I _{DRM}	<u> </u>	100	nanoamps
Peak On-State Voltage	$I_{TM} = 100 \text{ mA}$	V _{TM}	2.5	3.0	volts
Critical Rate-of-Rise of Off-State Voltage	$T_A = 85^{\circ}C$	dv/dt	12.0		volts/µsec.

coupled electrical characteristics (25°C)

		SYMBOL	TYP.	MAX.	UNITS
IRED Trigger Current, Current Required to Latch Output	MOC3020	I _{FT}	_	30	milliamps
(Main Terminal Voltage = 3.0 V, R_L = 150 Ω	MOC3021	I _{FT}	-	15	milliamps
(Wall Terminal Voltage = 3.0 V, Ng = 130 12	MOC3022	I _{FT}	-	10	milliamps
	MOC3023	I _{FT}		5	milliamps
Holding Current, Either Direction		I _H	100	<u> </u>	microamps

NOTE 1: Ratings apply to either polarity of Pin 6 — referenced to Pin 4. Voltages must be applied within dv/dt rating.